

OVERCOMING THE JARGON BARRIER

**ELEMENTARY
BAND
THEORY**

PHYSICIST

Solid state band

Valence band, VB

Conduction band, CB

Fermi energy, E_F

Bloch orbital, delocalized

n-doping

p-doping

Band gap, E_g

Direct band gap

Indirect band gap

Phonon or lattice vibration

Peierls distortion

CHEMIST

Molecular orbital

HOMO

LUMO

Chemical potential

Molecular orbital, localized

Reduction, pH scale base

Oxidation, pH scale acid

HOMO-LUMO gap

Dipole allowed

Dipole forbidden

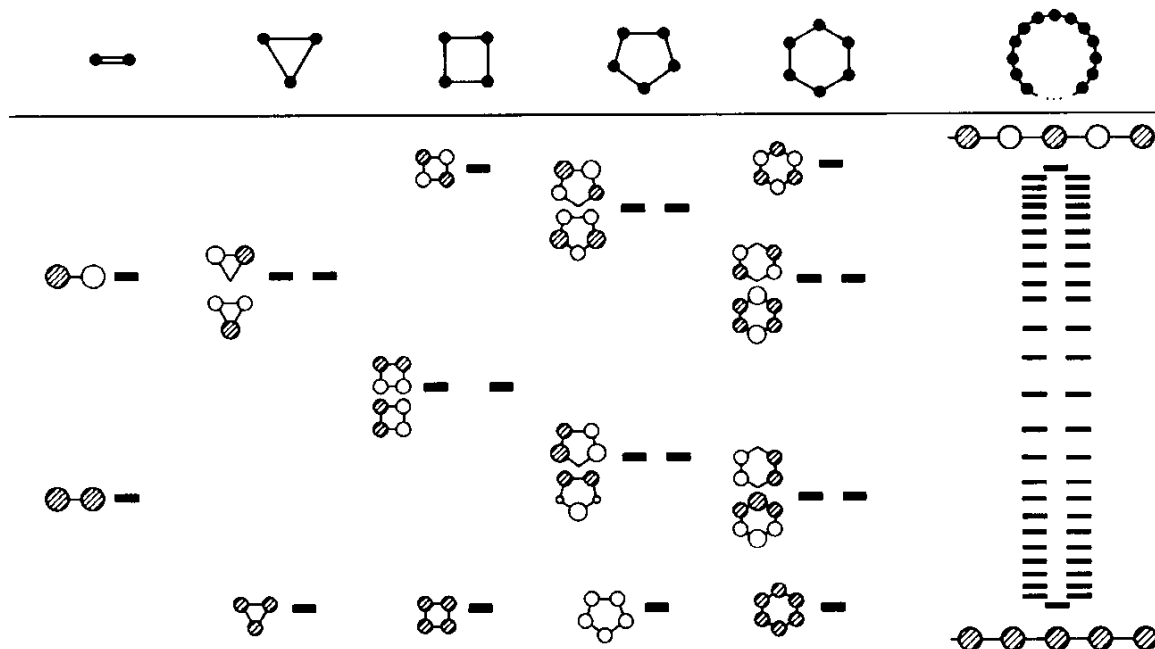
Vibrational mode

Jahn-Teller effect

Molecular orbital $\rightarrow\rightarrow\rightarrow\rightarrow\rightarrow\rightarrow\rightarrow\rightarrow$ Electronic band

N atomic orbitals combine to form bonding and antibonding molecular orbitals, N energy levels.

Large rings - cyclic boundary condition



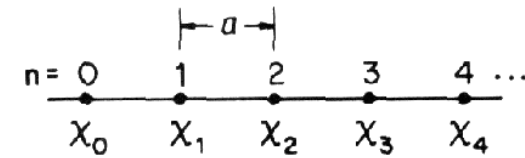
A rough rule of thumb: the separation of the energy levels in the dimer corresponds to about half width of the energy band.

Bloch functions, crystal orbitals

simple example:
infinite one-dimensional array of s-orbitals

k = wavevector,
 a = lattice constant,
 n = orbital counter

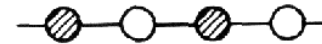
Large number of discrete levels = band



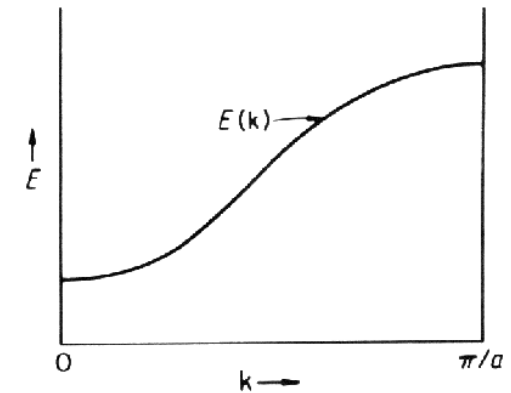
$$\psi_k = \sum_n e^{ikna} \chi_n$$

$$k = \frac{\pi}{a} \quad \psi_{\frac{\pi}{a}} = \sum_n e^{i\pi n} \chi_n = \sum_n (-1)^n \chi_n$$

$$= \chi_0 - \chi_1 + \chi_2 - \chi_3 + \dots$$



Antibonding



$$k = 0 \quad \psi_0 = \sum_n e^{i0} \chi_n = \sum_n \chi_n$$

$$= \chi_0 + \chi_1 + \chi_2 + \chi_3 + \dots$$



Bonding

Bandwidth or band dispersion:
energy difference between the highest and lowest level

Bandwidth increases with better orbital overlap

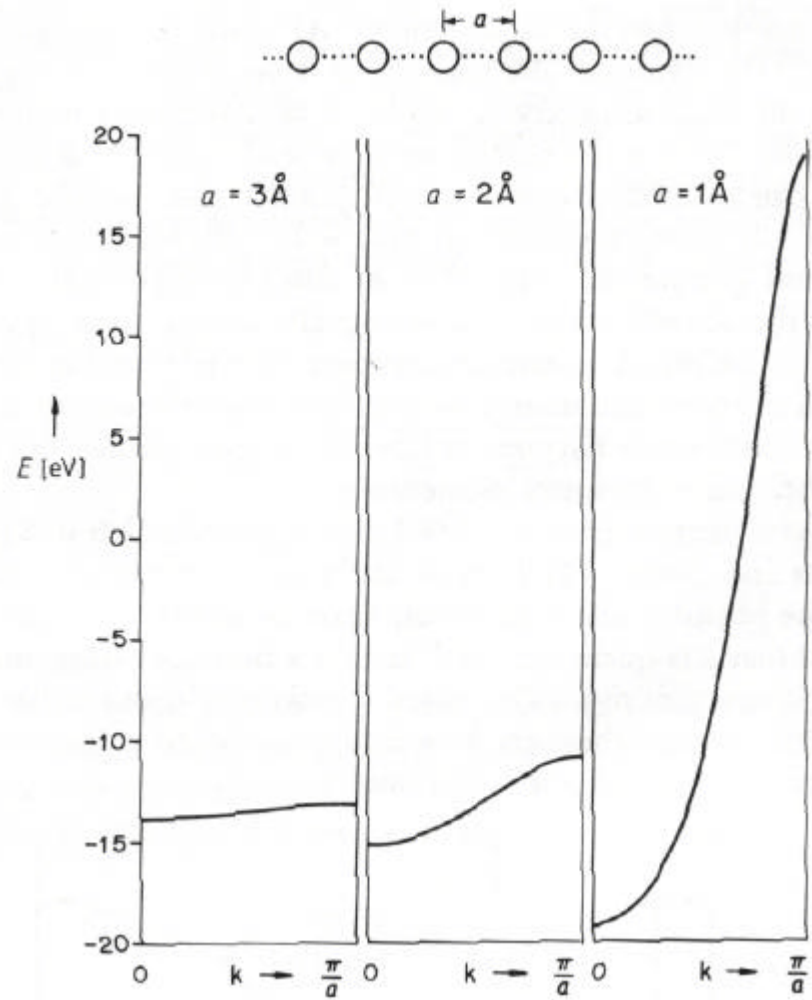
- shorter interatomic distance
- closer energy match
- topology
- density, oxides more diffuse than halides, wider bands
- localization of electrons – narrow bands

Bandwidth arising from $\sigma > \pi > \delta$ overlap

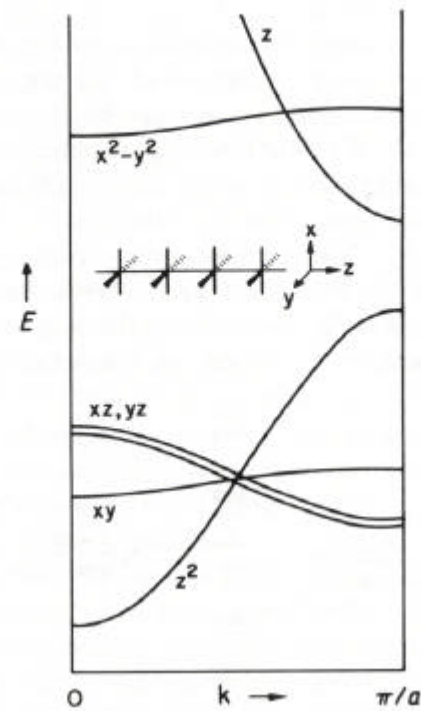
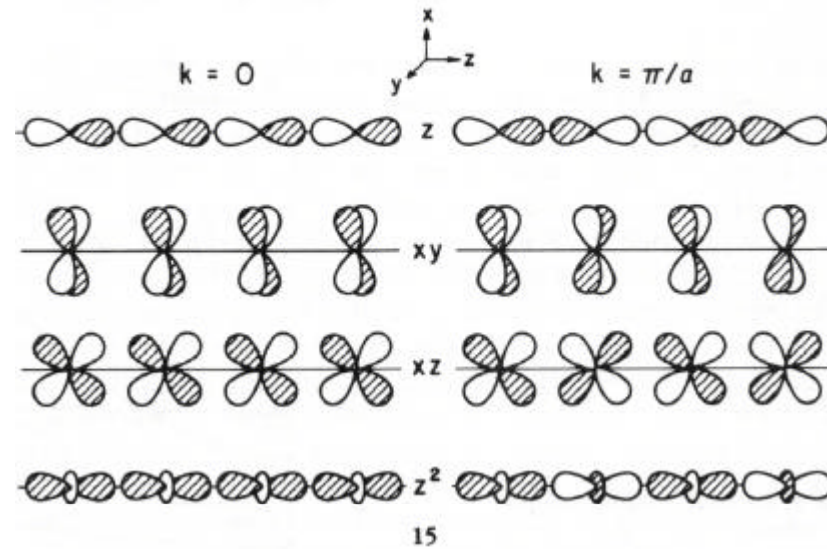
Core orbitals – narrow bands (0.1 eV), 4f in lanthanides

Valence orbitals, s, p – wide bands (10 eV)

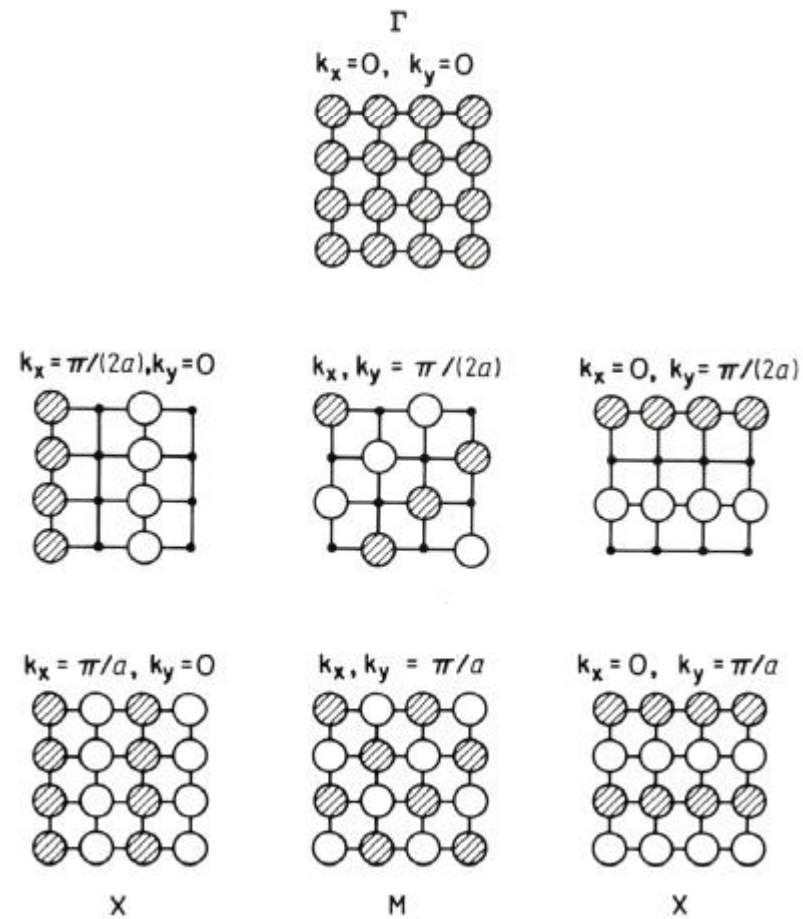
Bandwidth or band dispersion:
energy difference between the highest and lowest level



p, d-orbital interactions

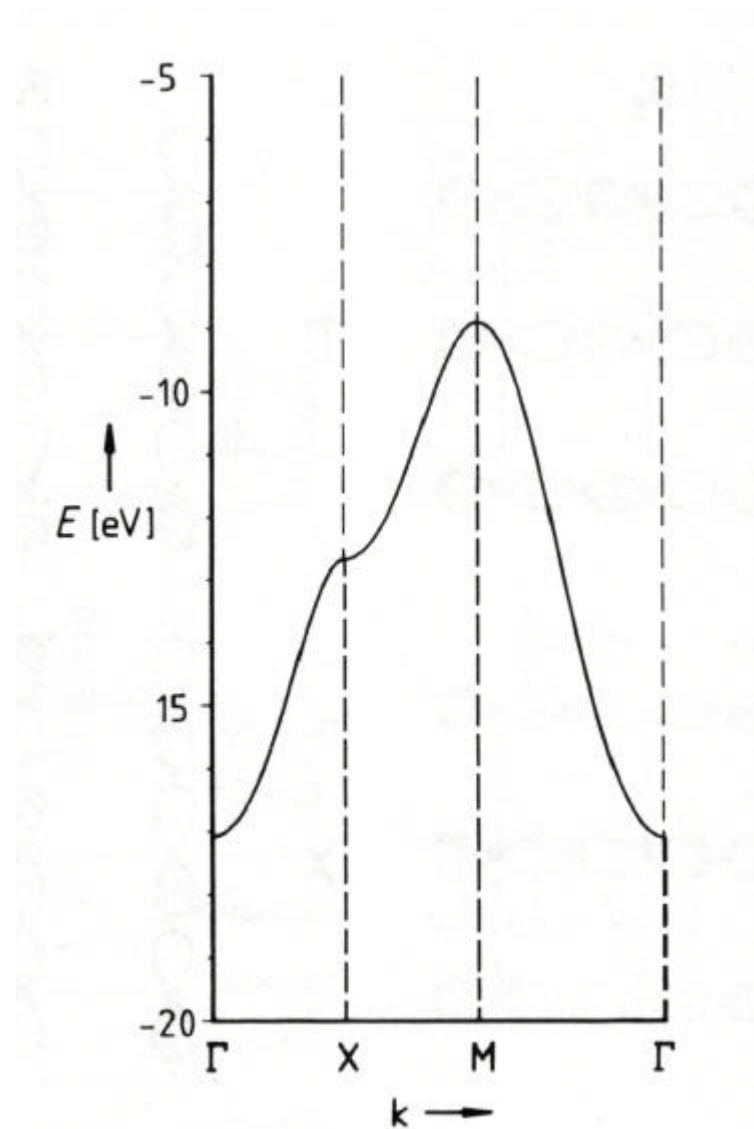


Two dimensional lattice



Two dimensional lattice

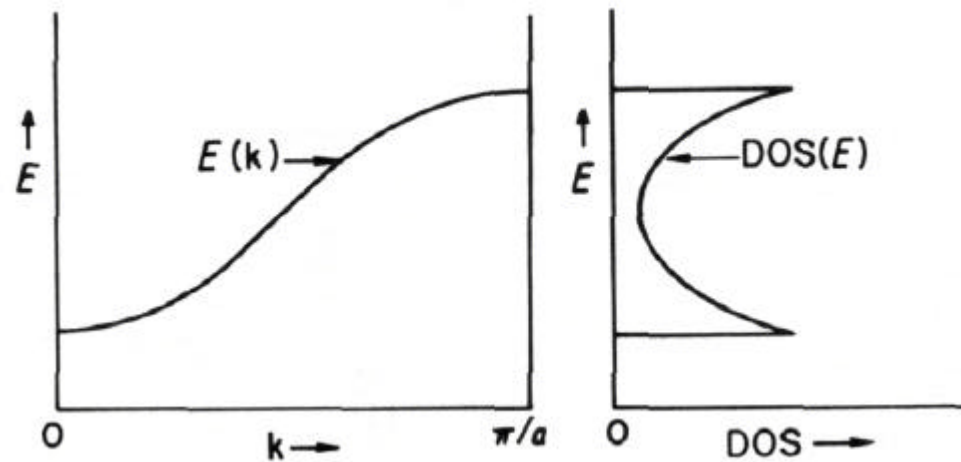
Band structure of a square lattice of H atoms
($d_{\text{HH}} = 2.0 \text{ \AA}$)



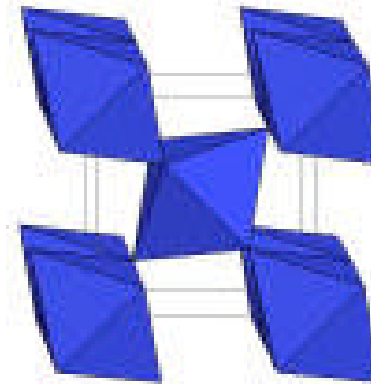
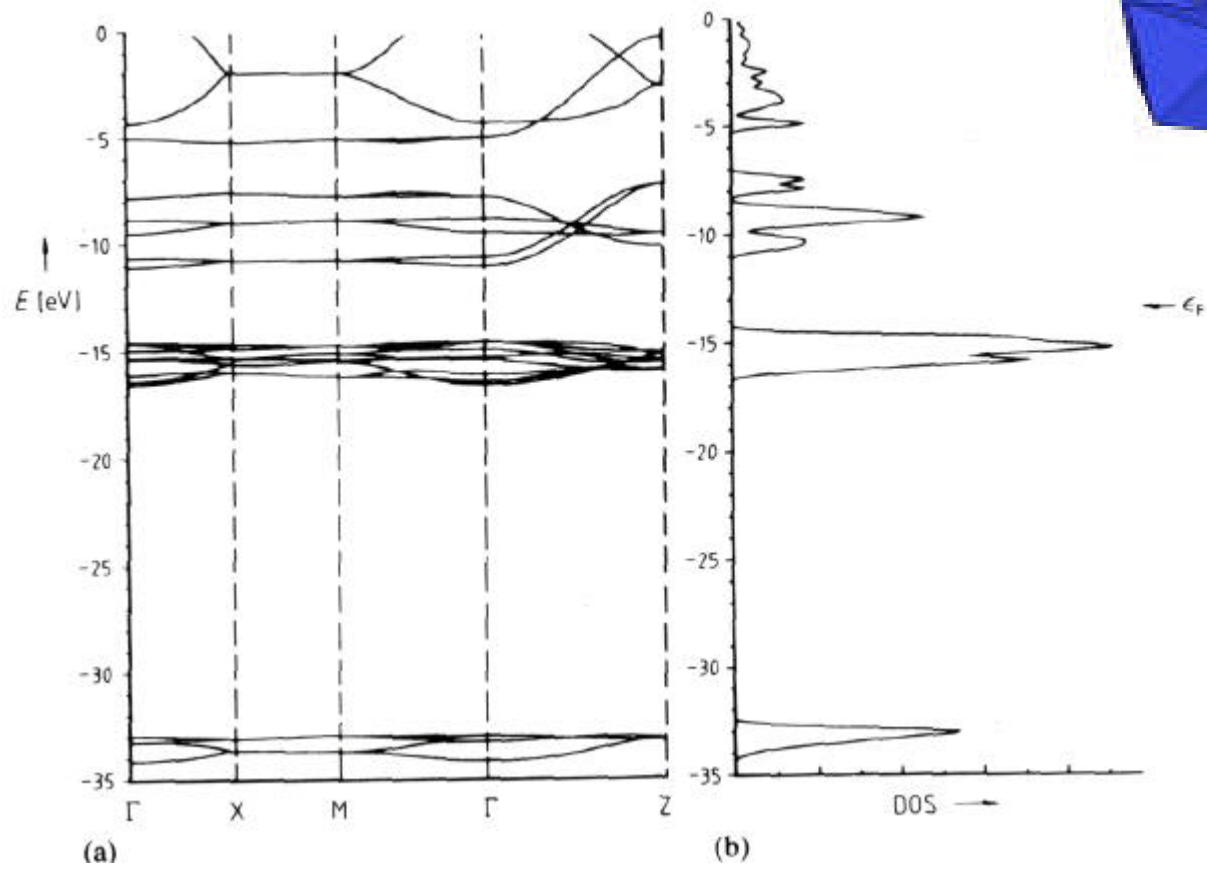
Density of states (DOS, $N(E) dE$)

Number of levels available for electrons at different energies per unit volume of the solid.

DOS is zero in the band gap



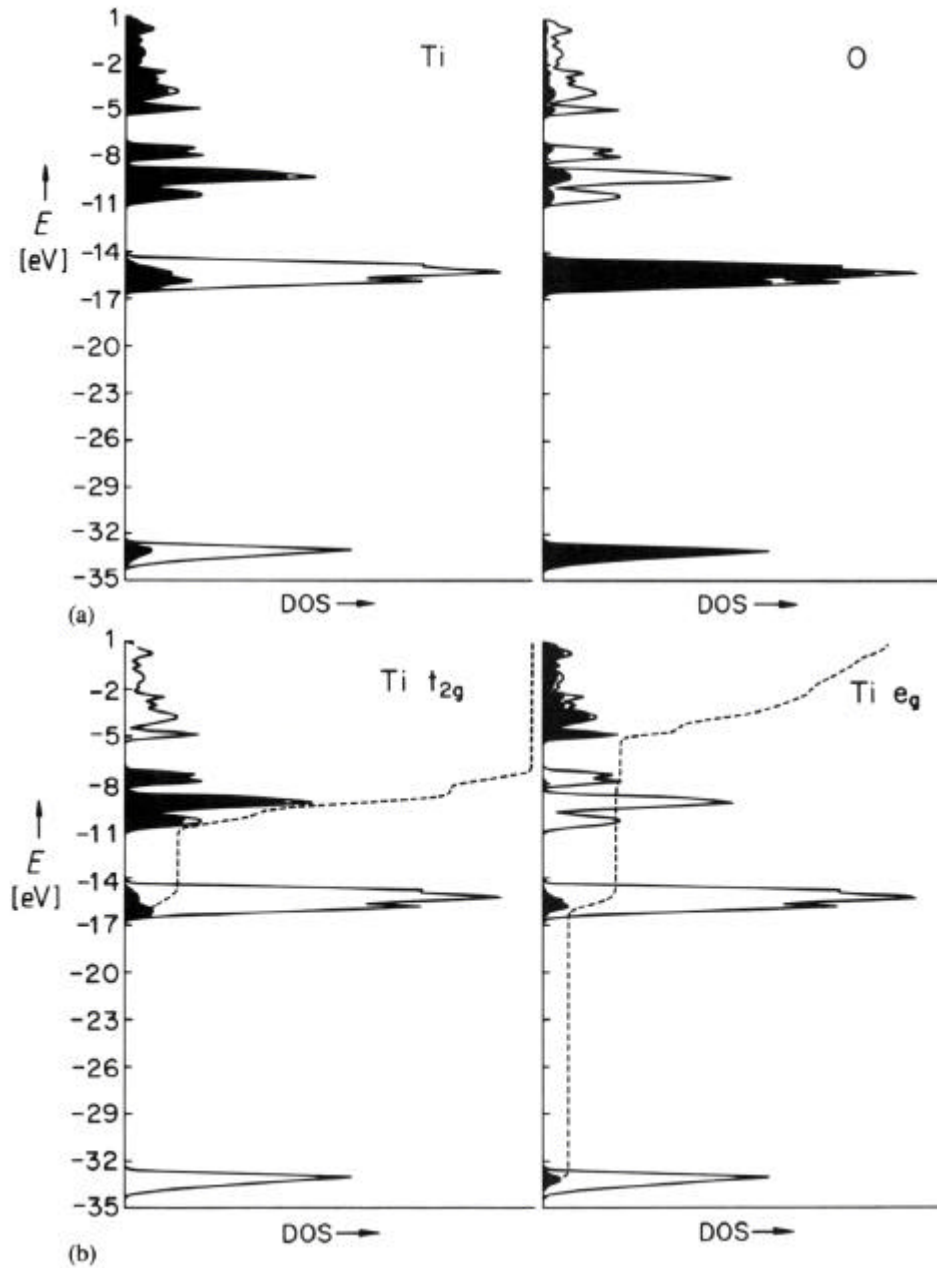
Rutile TiO_2
band structure (a) and DOS (b)



**Contributions to
the total DOS of rutile**

(a) Ti and O

(b) Ti d-orbitals, t_{2g} and e_g



Classification of solids

Molecular solids – N_2 , C_6H_6 , I_2 , ...

Van der Waals forces, little change from the gas phase, electronic bands correspond to empty and filled MOs of the individual molecules.

Ionic solids – NaCl , CaF_2 , NiO , ...

Charge transfer from cations to anions, energy bands made up from the atomic orbitals of cations and anions.

NaCl : 3p of Cl is the top filled band, 3s of Na is the lowest empty band.

Covalent solids – diamond, Si,

Overlap of orbitals and electron sharing between adjacent atoms.

Filled bands are made up from bonding MOs, empty bands are made up from antibonding MOs.

Metallic solids – Cu, Mg, W, TiO,

Simple metals – Na

Very strong overlap of atomic orbitals on adjacent atoms, arising bands are very broad, 3s, 3p, and 3d merge into a single wide band, electrons move freely, little attraction to the atomic cores.

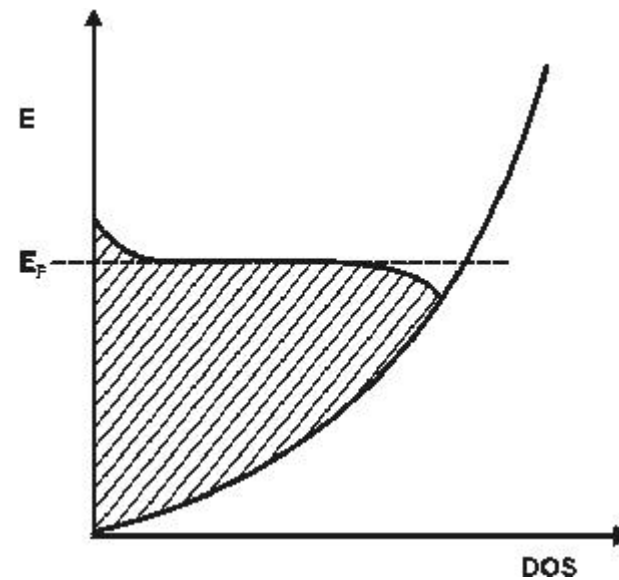
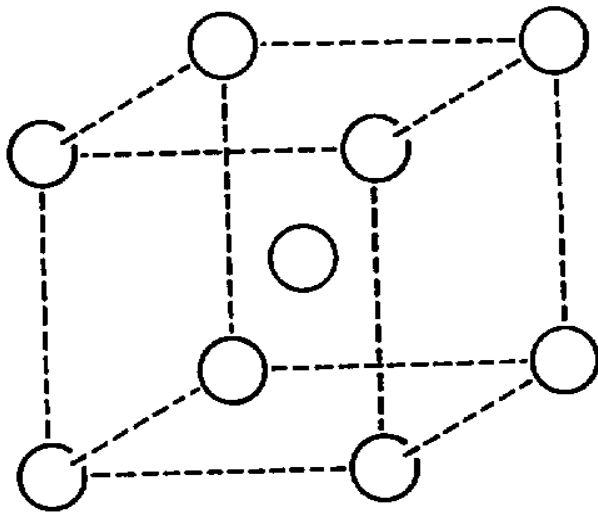
Fermi level

E_F = the thermodynamic chemical potential for electrons in the solid

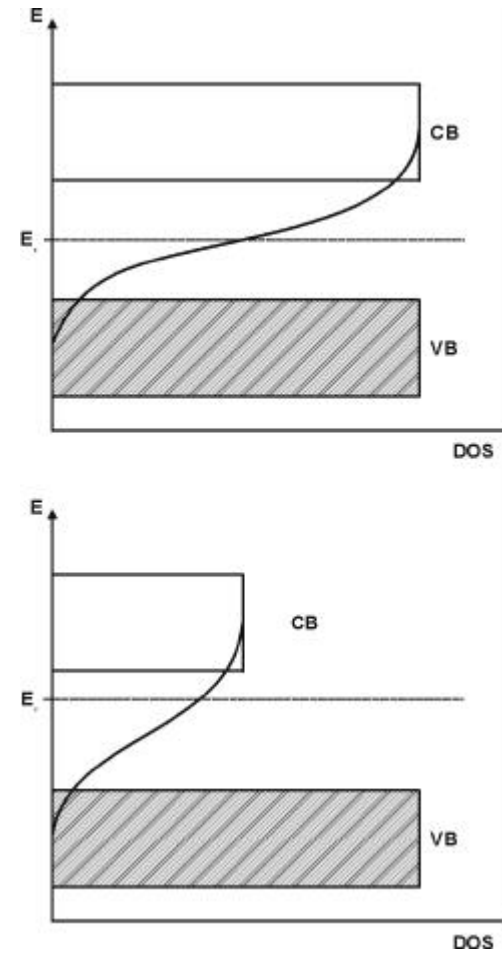
Metals – boundary between filled and unfilled levels

The Fermi-Dirac distribution function:

$$f(E) = 1/[1 + \exp\{(E - E_F)/kT\}]$$



Semiconductors



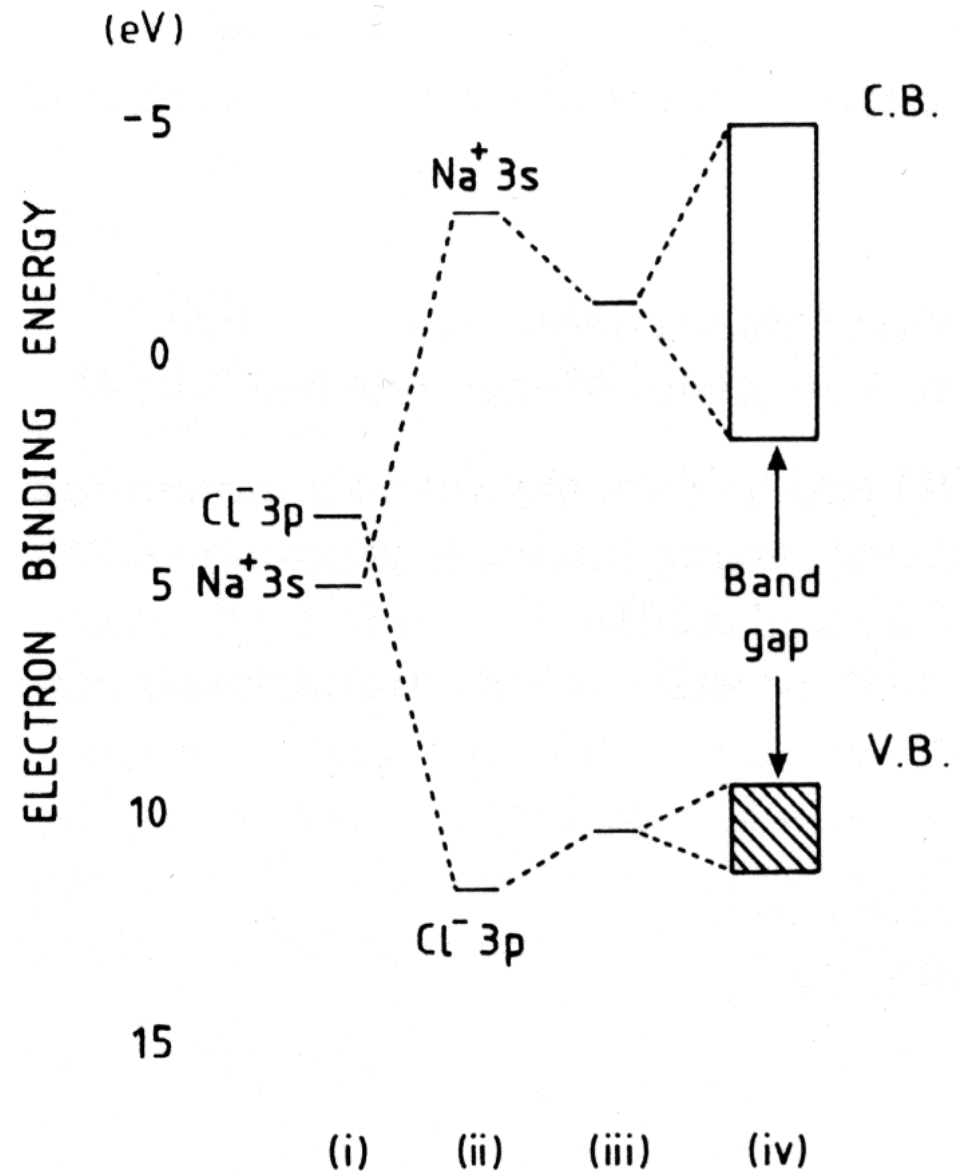
Ionic solids

Example NaCl, $E_g = 9 \text{ eV}$

i = ions in the gas phase

ii = ions in the lattice,
Madelung potential,
filled levels stabilized by positive
potential of cations,
empty levels destabilized

iii = polarization energy



Delocalized Bands – Localized Bonds

Molecules: Mulliken overlap population

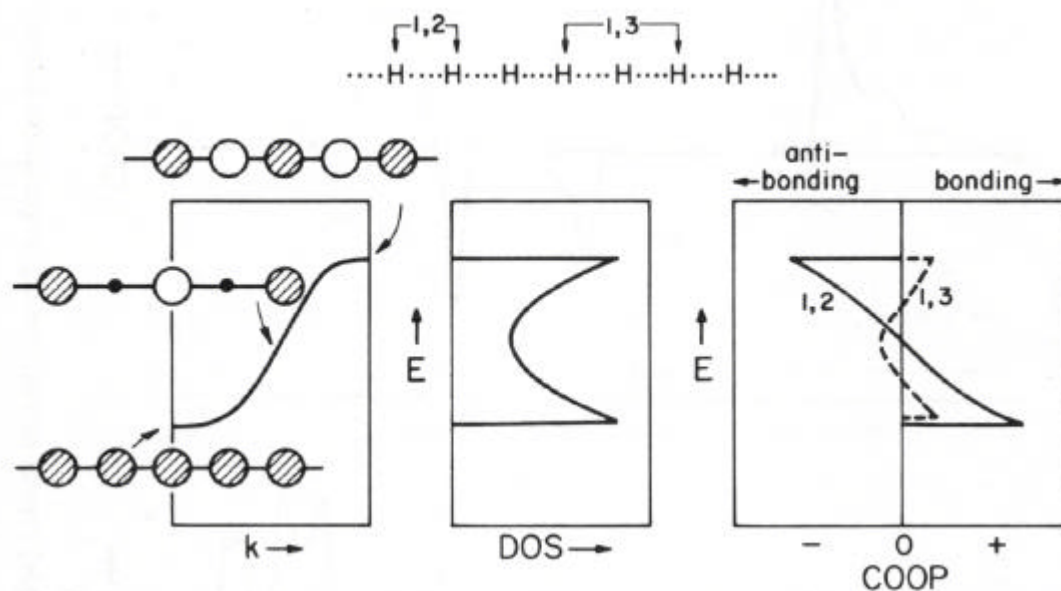
$$S_{12} = 2 c_1 c_2 S_{12}$$

c_1, c_2 same sign = bonding

c_1, c_2 opposite sign = antibonding

S_{12} overlap integral

Solids: Overlap population-weighted density of states = crystal orbital overlap population (COOP) – for a specific bond

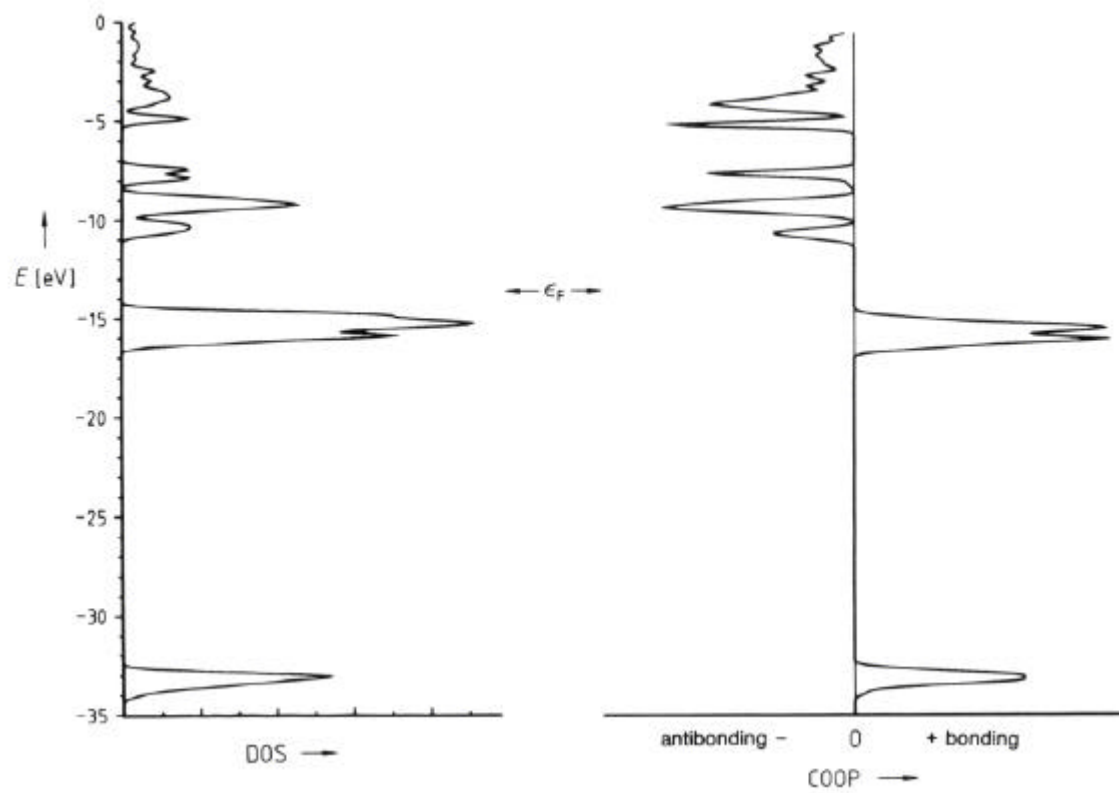


COOP curves

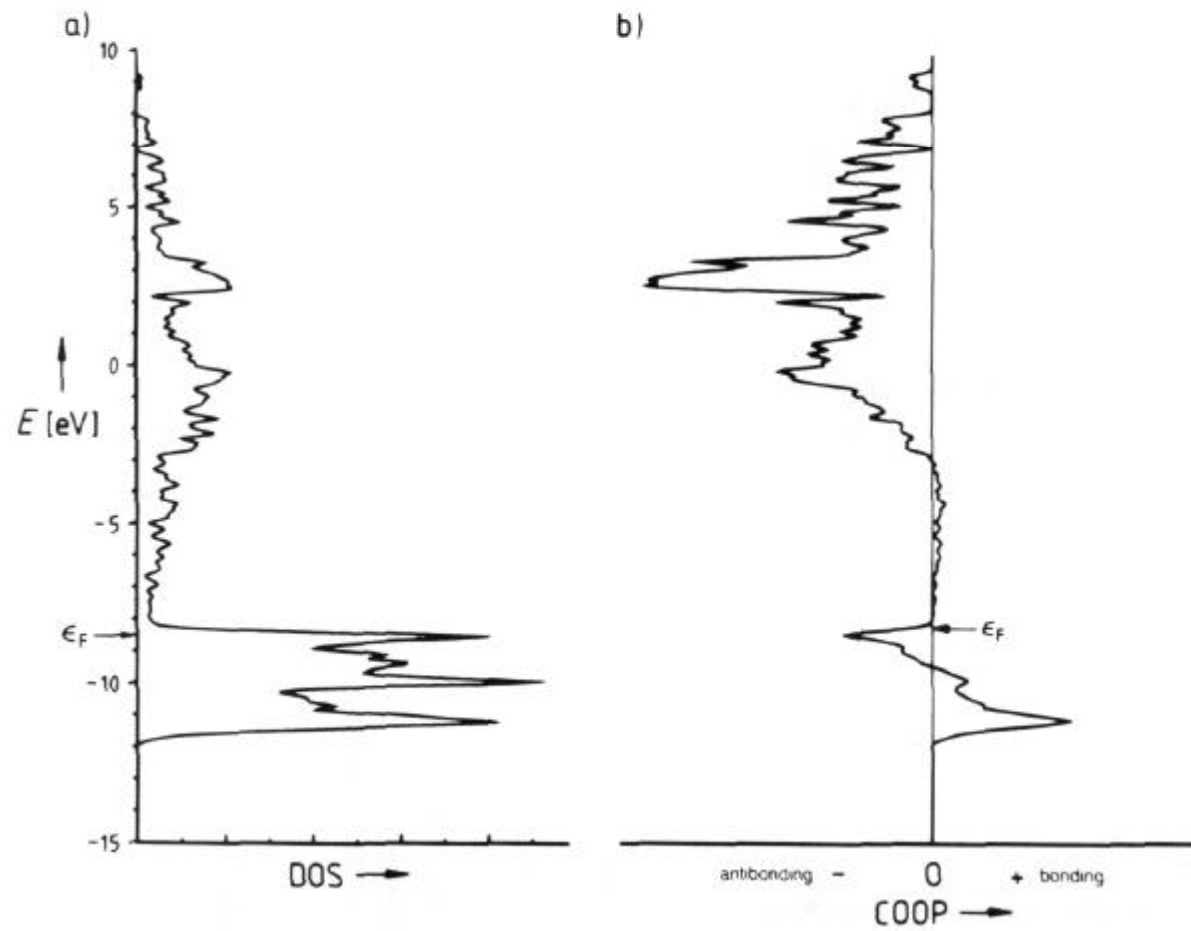
Sign – positive = bonding, negative = antibonding

Amplitude – depends on DOS, orbital overlap, MO coefficients

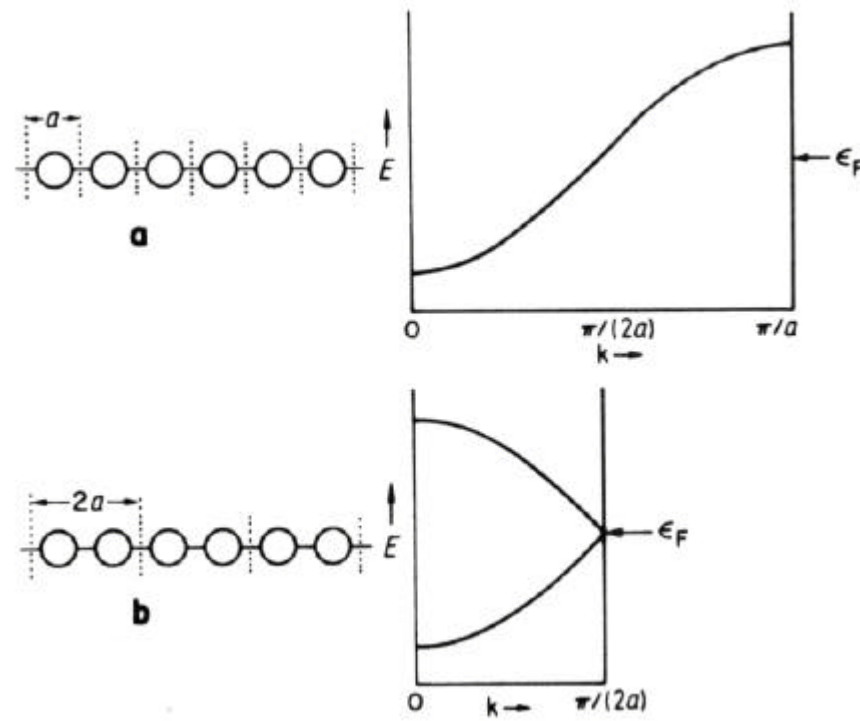
DOS and COOP for the Ti-O bonds in rutile



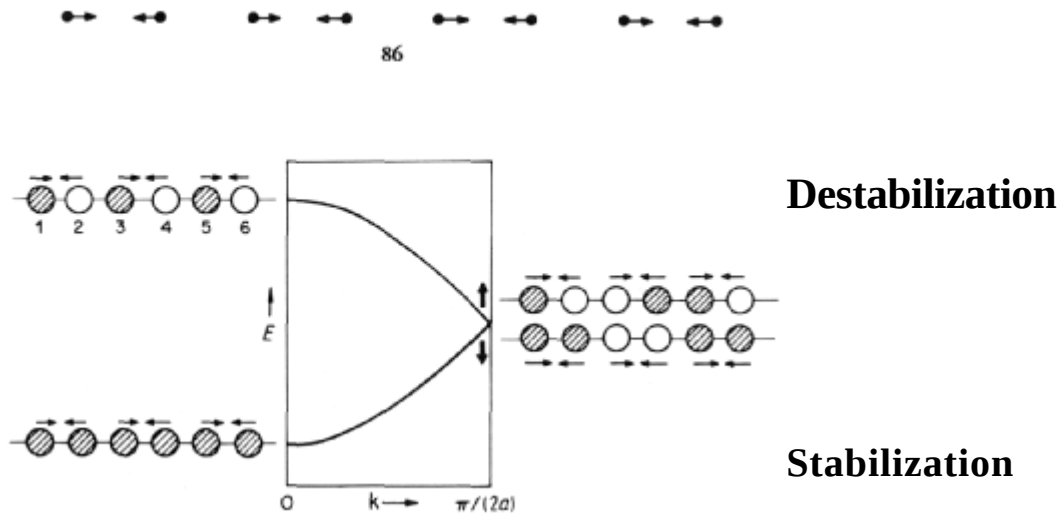
DOS and COOP for the Ni-Ni bonds in Ni metal



Peierls distortion



Peierls distortion – maximizing bonding, lowering the DOS at the Fermi level, bonding states down in energy, antibonding states up, a band gap opens at the Fermi level



Peierls distortion

